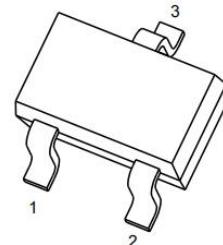


## PW2101

### 20V P-Channel MOSFET

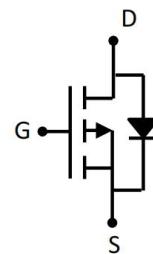
-1.4A -20V;  $R_{DS(ON)typ}=90m\Omega @ -4.5V$ ,  $R_{DS(ON)typ}=115m\Omega @ -2.5V$ ,  
 $R_{DS(ON)typ}=145m\Omega @ -1.8V$ .

SOT-323



1. GATE
2. SOURCE
3. DRAIN

Schematic diagram



#### FEATURE

- Leading Trench Technology for Low  $R_{DS(on)}$
- Extending Battery Life

#### Application

- High Side Load Switch
- Charging Circuit
- Single Cell Battery Applications such as Cell Phones, Digital Cameras ,PDAs, etc

#### MARKING:



#### ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 8.0$	V
Continuous Drain Current	$I_D$	-1.4	A
Pulsed Drain Current( $t_p=10\mu s$ )	$I_{DM}$	-3.0	A
Power Dissipation	$P_D$	0.29	W
Thermal Resistance from Junction to Ambient	$R_{0JA}$	431	$^\circ C/W$
Junction Temperature	$T_J$	150	$^\circ C$
Storage Temperature	$T_{STG}$	-55~+150	$^\circ C$

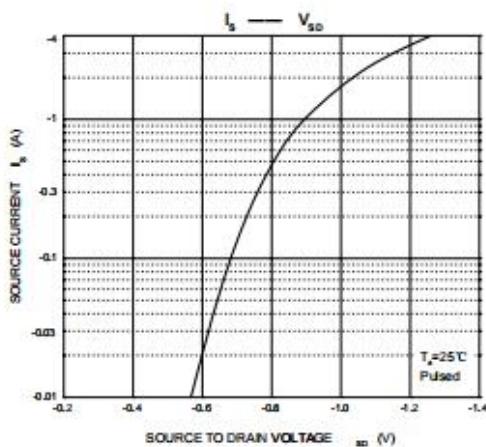
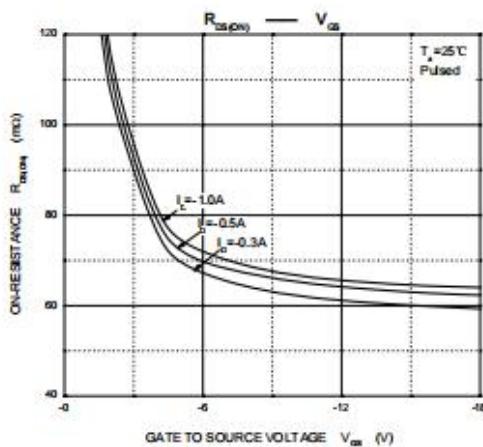
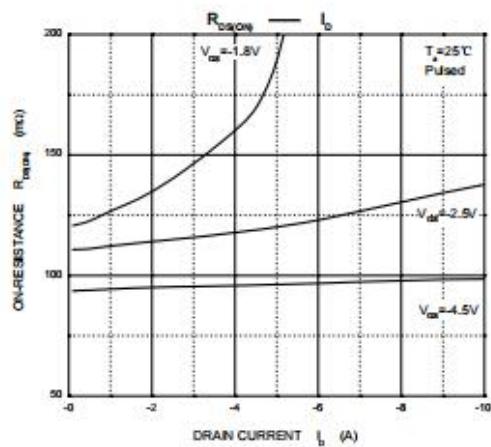
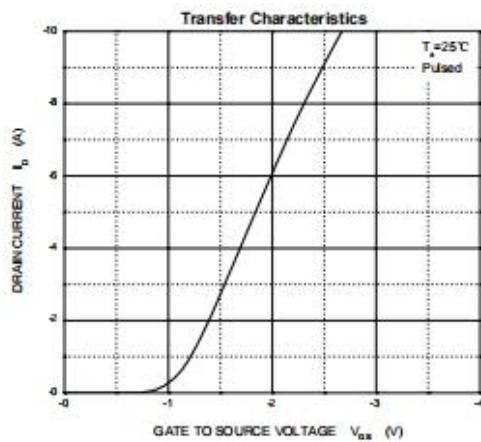
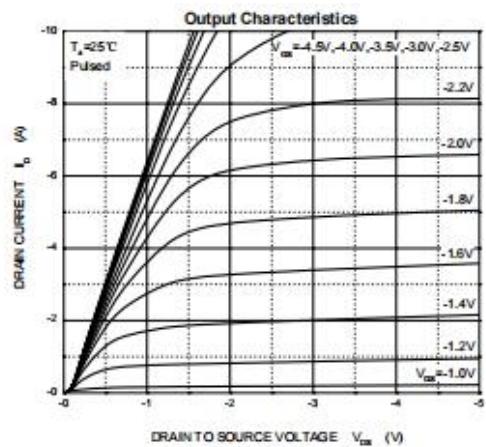
**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$	-20			V
Zero gate voltage drain current	$I_{\text{DSS}}$	$V_{\text{DS}} = -20\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
Gate-body leakage current	$I_{\text{GSS}}$	$V_{\text{GS}} = \pm 8\text{V}, V_{\text{DS}} = 0\text{V}$			$\pm 100$	nA
<b>ON CHARACTERISTICS<sup>(1)</sup></b>						
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$	-0.45	-0.65	-1.0	V
Drain-source on-resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -1.0\text{A}$		90	110	$\text{m}\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -0.5\text{A}$		115	140	
		$V_{\text{GS}} = -1.8\text{V}, I_{\text{D}} = -0.3\text{A}$		145	210	
Forward transconductance	$g_{\text{fs}}$	$V_{\text{DS}} = -10\text{V}, I_{\text{D}} = -0.8\text{A}$		2		S
<b>DYNAMIC CHARACTERISTICS<sup>(3)</sup></b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = -8\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		640		$\text{pF}$
Output Capacitance	$C_{\text{oss}}$			120		
Reverse Transfer Capacitance	$C_{\text{rss}}$			82		
<b>SWITCHING CHARACTERISTICS<sup>(2,3)</sup></b>						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, V_{\text{DD}} = -4.0\text{V}, I_{\text{D}} = -1.0\text{A}, R_{\text{G}} = 6.2\Omega$		6.2		$\text{nS}$
Turn-on rise time	$t_{\text{r}}$			15		
Turn-off delay time	$t_{\text{d}(\text{off})}$			26		
Turn-off fall time	$t_{\text{f}}$			18		
Total Gate Charge	$Q_{\text{g}}$	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -3.0\text{A}$		5.5	10	$\text{nC}$
				3.3	6	
Gate-Source Charge	$Q_{\text{gs}}$	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -3.0\text{A}$		0.7		
Gate-Drain Charge	$Q_{\text{gd}}$			1.3		
<b>SOURCE-DRAIN DIODE CHARACTERISTICS</b>						
Diode Forward voltage	$V_{\text{DS}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{S}} = -0.3\text{A}$			-1.2	V

**Notes :**

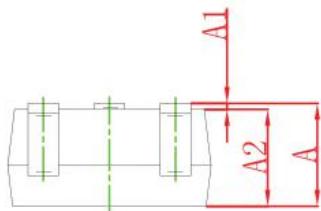
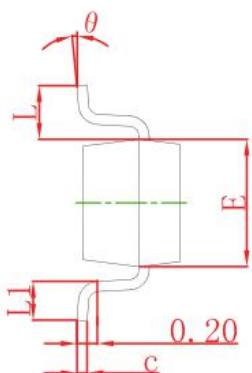
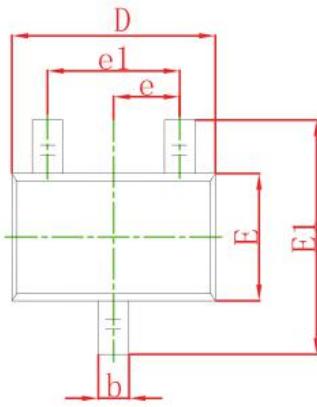
- 1.Pulse Test : pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- 2.Switching characteristics are independent of operating junction temperatures.
- 3.These parameters have no way to verify.

### Typical Electrical and Thermal Characteristics



SOT-323 Package Information

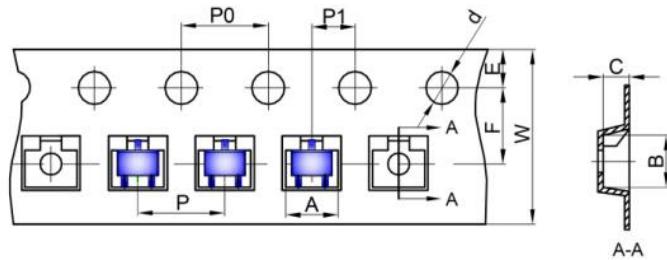
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Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

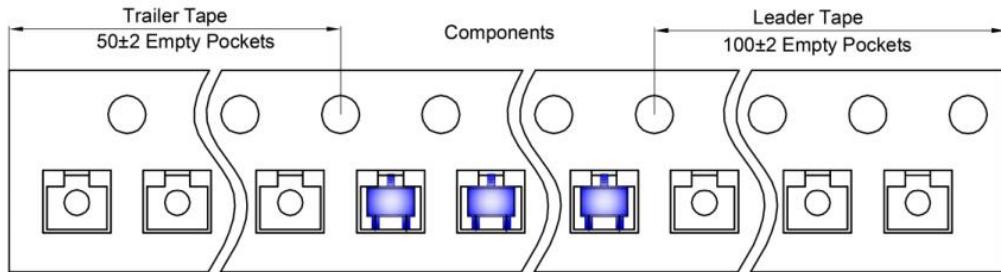
## SOT-323 Tape and Reel

### SOT-323 Embossed Carrier Tape

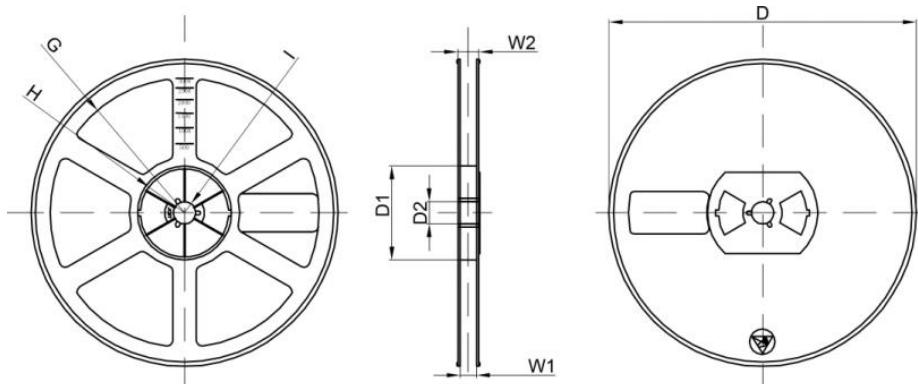


Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOT-323	2.25	2.55	1.19	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

### SOT-323 Tape Leader and Trailer



### SOT-323 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	